





Part Mark on

00 СВ

Rounded Face

Ejection Mark

#### 400V PNP MEDIUM POWER HIGH VOLTAGE TRANSISTOR IN E-LINE

#### **Features**

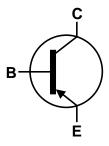
- BV<sub>CEO</sub> > -400V
- I<sub>C</sub> = -0.5A High Continuous Collector Current
- I<sub>CM</sub> = -1A Peak Pulse Current
- T<sub>J</sub> up to +200°C for High Temperature Operation
- Low Saturation Voltage < -0.25V @ -50mA
- P<sub>D</sub> = 1W Power dissipation
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

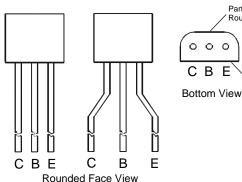
- Case: E-Line (TO-92 Compatible)
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3:
- Weight: 0.159 grams (approximate)







Device Symbol



Pin-Out Configuration

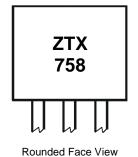
## **Ordering Information** (Notes 4)

Part Number	Compliance	Marking	Case	Leads	Quantity
ZTX758	AEC-Q101	ZTX758	E-Line	Straight	4,000 loose in a Box
ZTX758STZ	AEC-Q101	ZTX758	E-Line	Joggled	2,000 taped per Ammo Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

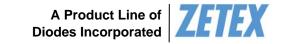
### **Marking Information**



ZTX758 = Product Type Marking Code

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#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-400	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-400	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-0.5	А
Peak Pulse Current	Ісм	-1	Α

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1.5	W
Power Dissipation (Note 6)	P <sub>D</sub>	1	W
Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	116	°C/W
Thermal Resistance Junction to Ambient (Note 6)	R <sub>θJA</sub>	175	°C/W
Thermal Resistance Junction to Lead (Note 7)	R <sub>θJL</sub>	70	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +200	°C

### ESD Ratings (Note 8)

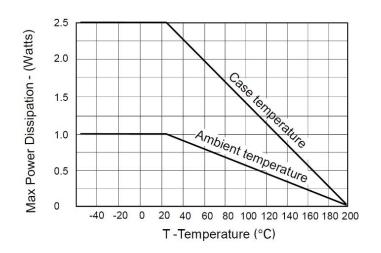
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

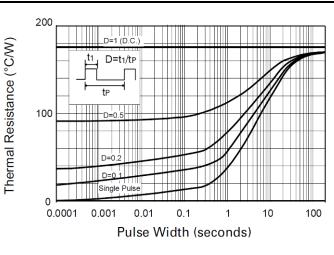
Notes:

- 5. For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
- 7. Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

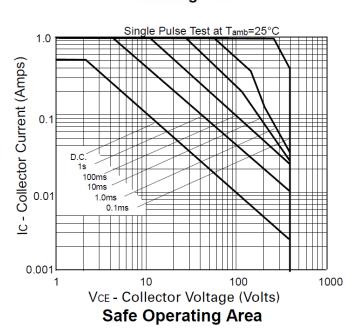


### **Thermal Characteristics and Derating Information**





## **Derating curve**



Maximum transient thermal impedance





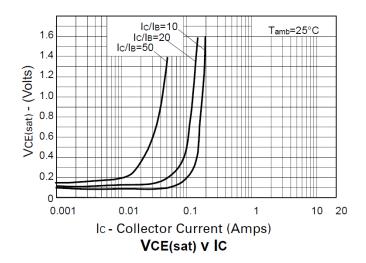
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

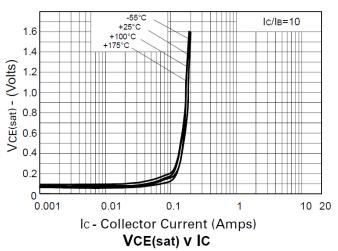
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-400	_	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-400	_	_	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector Cut-off Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -320V
Emitter Cut-off Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -6V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	I	_	-300 -250 -500	mV	$I_{C}$ = -20mA, $I_{B}$ = -1mA $I_{C}$ =-50mA, $I_{B}$ = -5mA $I_{C}$ =-100mA, $I_{B}$ = -10mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	_	-0.9	V	$I_C = -100 \text{mA}, I_B = -100 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	_	-0.9	V	$I_C = -100 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Gain (Note 9)	h <sub>FE</sub>	50 50 40	_	_	_	$I_{C}$ = -1mA, $V_{CE}$ = -5V $I_{C}$ = -100mA, $V_{CE}$ = -5V $I_{C}$ = -200mA, $V_{CE}$ = -10V
Current Gain-Bandwidth Product (Note 9)	f <sub>T</sub>	50	_	_	MHz	$V_{CE} = -20V$ , $I_{C} = -20mA$ f = 20MHz
Output Capacitance (Note 9)	C <sub>obo</sub>	_	_	20	pF	V <sub>CB</sub> = -20V. f = 1MHz
Turn-On Times	t <sub>on</sub>	_	140	_	ns	I <sub>C</sub> = -100mA, I <sub>B1</sub> = 10mA,
Turn-Off Times	t <sub>off</sub>	_	2000	_	ns	$I_{B2} = -20 \text{mA}, V_C = -100 \text{V}$

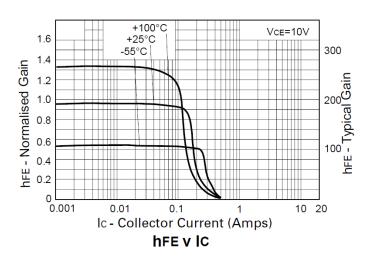
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

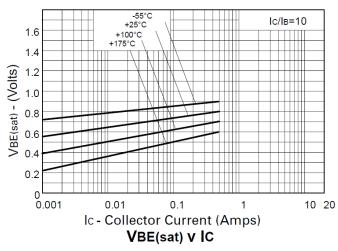


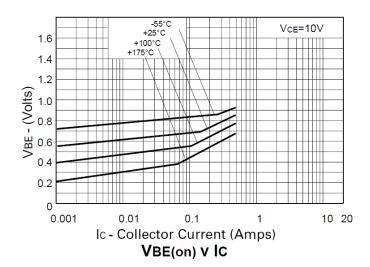
#### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









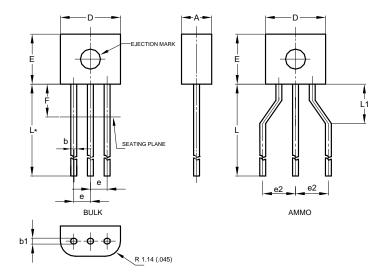






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



E-Line						
Dim	Min	Min Max				
Α	2.16	2.41	_			
b	0.41	0.495	-			
b1	0.41	0.495	_			
D	4.37	4.77	-			
Е	3.61	4.01	_			
е	_	_	1.27			
e2	_	_	2.54			
F	_	2.50	_			
٦	13.00	13.97	_			
L1	2.50	3.50	_			
All Dimensions in mm						





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